

## High Power PIN Diodes

V12

### Features

- ◆ High Power Handling
- ◆ Low Loss / Low Distortion
- ◆ Voltage Ratings up to 1000 Volts
- ◆ Passivated Chip for Low Leakage Current
- ◆ Low Theta ( $\theta$ ) Due to Full Face Chip Bonding
- ◆ Leadless Low Inductance MELF Packages
- ◆ Various Package Options
- ◆ Available as Chips
- ◆ Fully RoHS Compliant

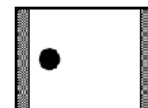
### Description

M/A-COM Technology Solutions MELF and HIPAX PIN diode series are designed for usage in switch and attenuator applications requiring high power handling and low distortion. The MELF and HIPAX PIN diodes incorporate a fully passivated PIN diode chip resulting in an extremely low reverse bias leakage current. The semiconductor technology utilized in the MELF and HIPAX families draws on M/A-COM Tech's substantial experience in PIN diode design and wafer fabrication. The result is a device which has a thick I-region and long carrier lifetime while maintaining low series resistance and capacitance values. The chips of the MELF and HIPAX PIN diodes are enclosed in a rugged ceramic package and is full face bonded to metal pins on both the anode and cathode. The result is a low loss PIN diode with low thermal resistance due to symmetrical thermal paths. The parts are offered in either magnetic or non-magnetic, HIPAX (axial leaded) or **Metal Electrode Leadless Faced (MELF)** surface mount packages for MRI applications. The MELF is a rectangular SMQ, package which is designed for high volume tape and reel assembly. This easy to use package design makes automatic pick and place, indexing and assembly, extremely easy. The parallel flat surfaces are suitable for most key jaw or vacuum pick-up techniques. All of the solderable surfaces are tin plated and compatible with industry standard reflow and vapor phase soldering processes. See page 7 of Application Note [M538](#) on the [M/A-COM Technology Solutions](#) website for a typical solder reflow profile.

### Package Styles



401 &amp; 402



1072 &amp; 1091

### Applications

HIPAX PIN diodes are designed for use in a wide variety of switch and attenuator applications from HF through UHF frequencies and at power levels above 1kW, CW. The internal chip as well as each diode assembly has been comprehensively tested and characterized to ensure predictable and repeatable performance.

### Design Recommendations

- ◆ Low Distortion Attenuators
  - MA4P4301B
- ◆ Surface Mount Switches
  - MA4P7101F
- ◆ Cellular Radio Antenna Switches
  - MA4P1200, MA4P1250

### Absolute Maximum Ratings

 $T_{AMB} = +25^{\circ}\text{C}$  (Unless Otherwise Noted) <sup>1</sup>

Parameter	Absolute Maximum
D.C. Reverse Voltage ( $V_R$ )	(See Tables)
Operating Chip Junction Temperature	-55°C to +175°C
Storage Temperature	-55°C to +200°C
Installation Temperature	+280°C for 30 Seconds
ESD	Class 1A, HBM

### Notes

1. Operation of this device above any one of these parameters may cause permanent damage.

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### MA4P1000 Series Electrical Specifications @ T<sub>AMB</sub> = +25°C

Part Number (NM Indicates Non-Magnetic)	V <sub>R</sub> Reverse Voltage V <sub>DC</sub>		C <sub>T</sub> Total Capacitance pF		R <sub>S</sub> Series Resistance Ω		R <sub>P</sub> Parallel Resistance kΩ
	<u>Condition</u> I <sub>R</sub> = 10 μA		<u>Conditions</u> f = 1 MHz V <sub>R</sub> = 50 V		<u>Conditions</u> f = 100 MHz I <sub>F</sub> = 50 mA		<u>Conditions</u> f = 100 MHz V <sub>R</sub> = 0 V
	MINIMUM	MAXIMUM RATING	TYPICAL	MAXIMUM	TYPICAL	MAXIMUM	MINIMUM
MA4P1200 - 401T	50	100	1.2	1.5	0.5	0.75	5
MA4P1200NM - 401T	50	100	1.2	1.5	0.5	0.75	5
MA4P1250 -1072T	50	100	0.8	1.2	0.5	0.75	5
MA4P1250NM -1072T	50	100	0.8	1.2	0.5	0.75	5
MA4P1450 -1091T	50	100	1.8	2.5	0.5	0.75	5
MA4P1450NM -1091T	50	100	1.8	2.5	0.5	0.75	5

Part Number (NM Indicates Non-Magnetic)	V <sub>F</sub> Forward Voltage (Max. I <sub>Forward</sub> @ 1V ≤ 1.5A)		T <sub>L</sub> Carrier Lifetime		Forward Bias Harmonic Distortion R(2a/a) * R(3a/a)		Reverse Bias Harmonic Distortion R(2a/a) – R(3a/a)	
	<u>Condition</u> I <sub>F</sub> = 50 mA		<u>Conditions</u> I <sub>F</sub> = 10 mA		<u>Conditions</u> f = 100 MHz		<u>Conditions</u> f = 100 MHz	
	TYPICAL	MAXIMUM RATING	MINIMUM	TYPICAL	MINIMUM	TYPICAL	MINIMUM	TYPICAL
MA4P1200 - 401T	0.85	1.0	2	8	80	90	60	70
MA4P1200NM - 401T	0.85	1.0	2	8	80	90	60	70
MA4P1250 -1072T	0.85	1.0	2	8	80	90	60	70
MA4P1250NM -1072T	0.85	1.0	2	8	80	90	60	70
MA4P1450 -1091T	0.85	1.0	2	8	80	90	60	70
MA4P1450NM -1091T	0.85	1.0	2	8	80	90	60	70

### Power Dissipation and Thermal Resistance Ratings @ T<sub>AMB</sub> = +25°C

Package Style	CONDITION	MA4P1200(NM)-401T		MA4P1250(NM)-1072T		MA4P1450(NM)-1091T	
		P <sub>DISS</sub>	θ <sub>JC</sub>	P <sub>DISS</sub>	θ <sub>JC</sub>	P <sub>DISS</sub>	θ <sub>JC</sub>
B Axial Lead	No Heatsink	1.5 W	15°C/W	—	—	—	—
	Lead Length 1/4"	5.5W		—	—	—	—
F MELF	No Heatsink			6W	15°C/W	10W	5°C/W
	Infinite Heatsink			18W		30W	

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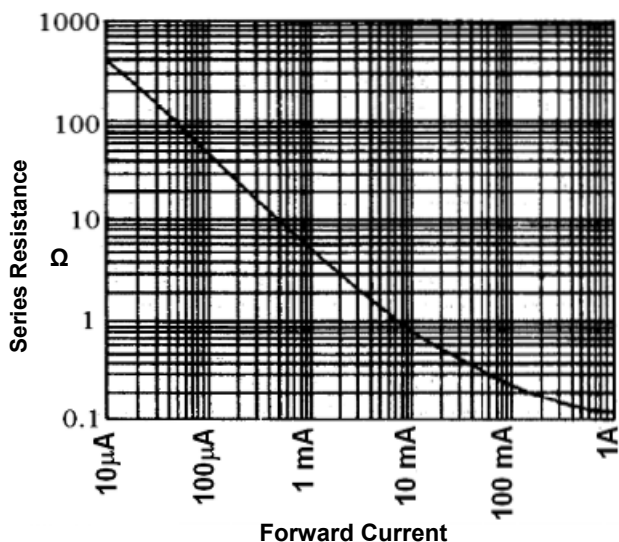
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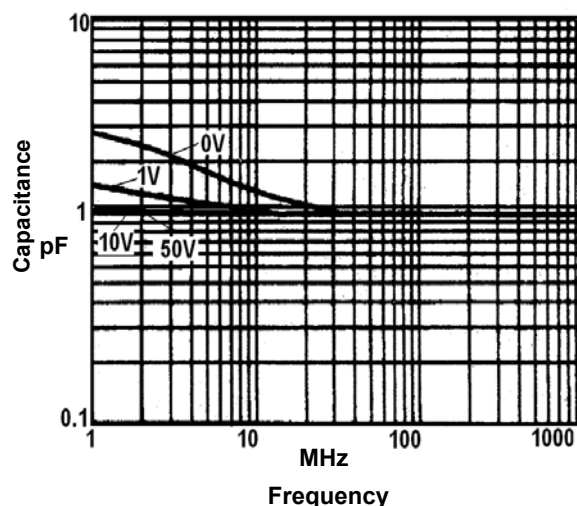
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### Typical Performance Curves @ $T_{AMB} = +25^{\circ}\text{C}$ MA4P1200 Series

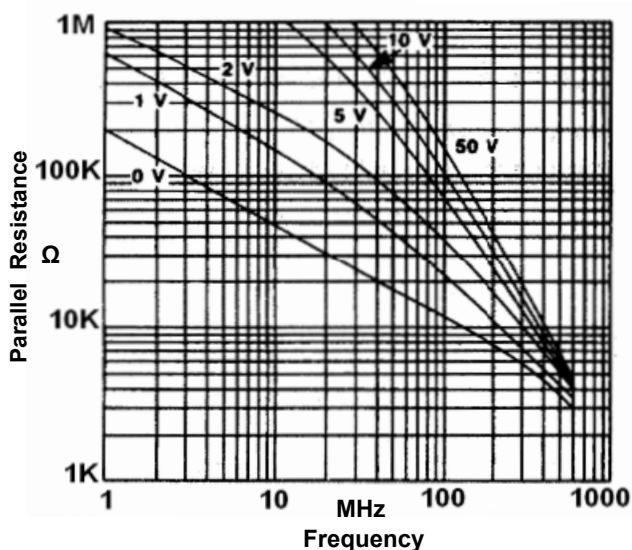
Series Resistance @ 100 MHz vs. Forward Current



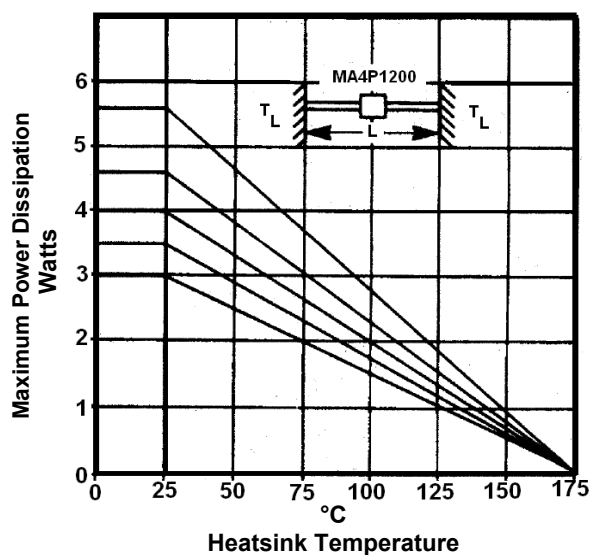
Capacitance vs. Frequency & Reverse Bias



Parallel Resistance vs. Frequency & Reverse Bias



Heatsink Temperature vs. Max. Power Dissipation

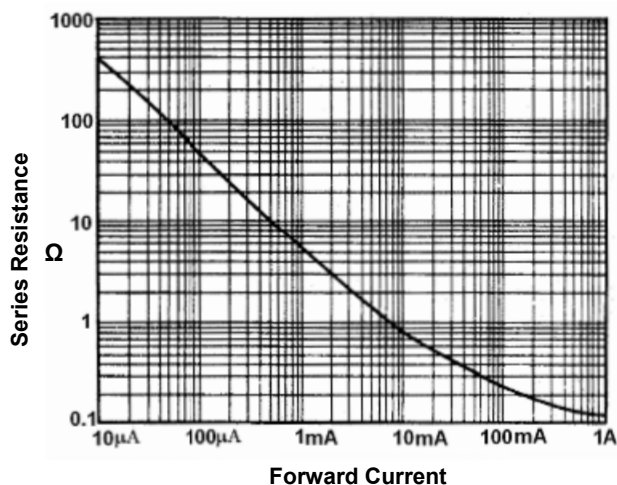


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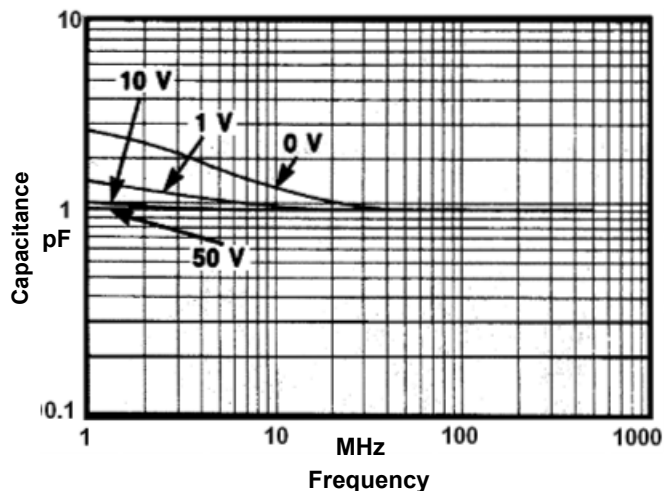
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### Typical Performance Curves @ $T_{AMB} = +25^{\circ}\text{C}$ MA4P1250 Series

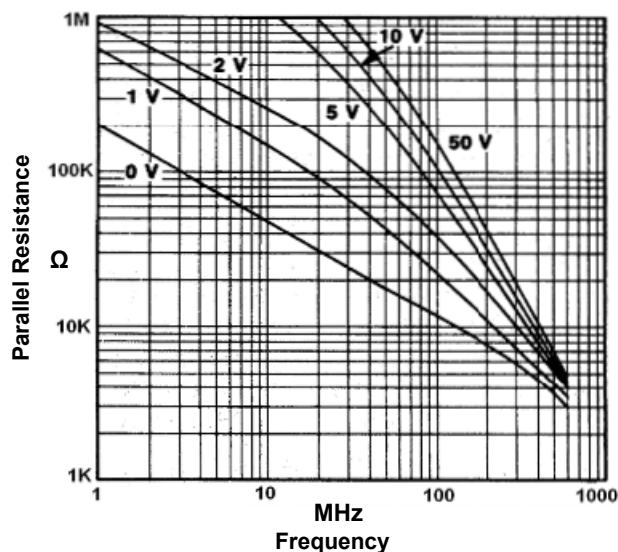
Series Resistance @ 100 MHz vs. Forward Current



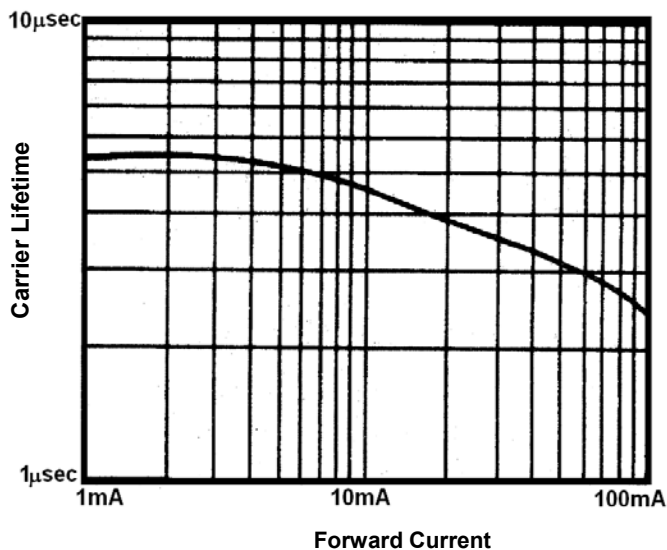
Capacitance vs. Frequency & Reverse Bias



Parallel Resistance vs. Frequency & Reverse Bias



Carrier Lifetime vs. Forward Bias Current



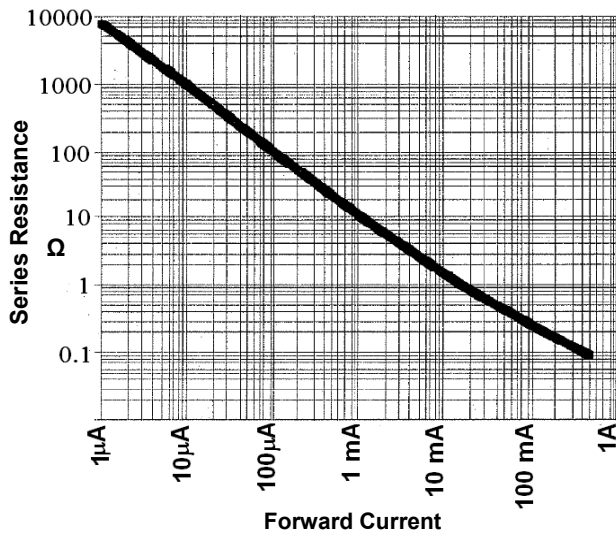


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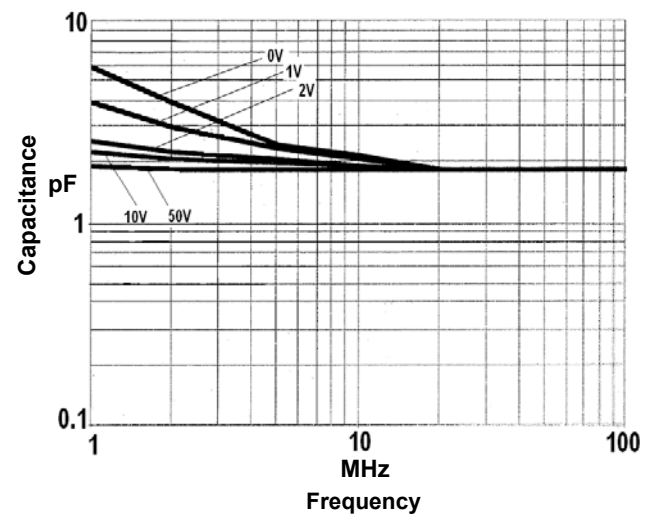
V12

### Typical Performance Curves @ $T_{AMB} = +25^{\circ}\text{C}$ MA4P1450 Series

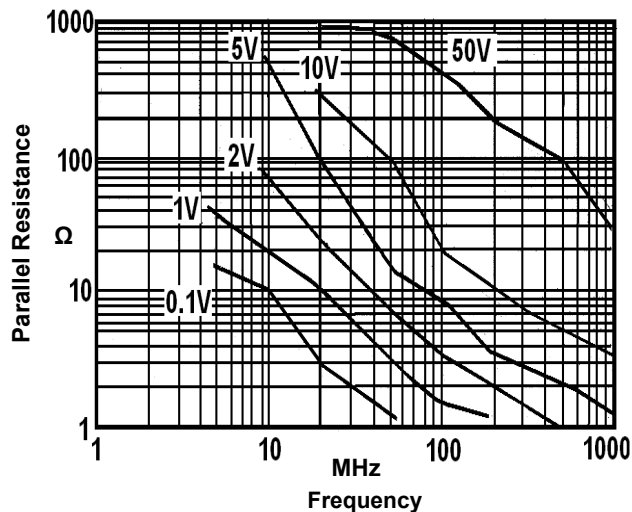
Series Resistance @ 100 MHz vs. Forward Current



Capacitance vs. Frequency and Reverse Bias



Parallel Resistance vs. Frequency and Reverse Bias



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### MA4P4000 - MA4P7100 Series Electrical Specifications @ $T_{AMB} = +25^{\circ}\text{C}$

Parameter	Symbol	Condition	MA4P4000	MA4P4300	MA4P7000	MA4P7100
Maximum Series Resistance	$R_S$	$I_F = 100 \text{ mA}$	$0.5 \Omega$	$1.0 \Omega$	$0.9 \Omega$	$0.5 \Omega$
Maximum Total Capacitance	$C_T$	$V_R = 100 \text{ V}$	$2.2 \text{ pF}$	$2.0 \text{ pF}$	$0.7 \text{ pF}$	$1.0 \text{ pF}$
Minimum Parallel Resistance	$R_P$	$V_R = 100 \text{ V}$	$20 \text{ k}\Omega$	$50 \text{ k}\Omega$	$200 \text{ k}\Omega$	$100 \text{ k}\Omega$
Minimum Carrier Lifetime	$T_L$	$I_F = 10 \text{ mA}$	$20 \mu\text{s}$	$15 \mu\text{s}$	$5 \mu\text{s}$	$2.5 \mu\text{s}$
Maximum Forward Voltage	$V_F$	$I_F = 100 \text{ mA}$	$1.0 \text{ V}$	$1.2 \text{ V}$	$1.0 \text{ V}$	$1.0 \text{ V}$
Maximum Reverse Current	$I_R$	At Maximum Rated	$1 \mu\text{A}$	$1 \mu\text{A}$	$1 \mu\text{A}$	$1 \mu\text{A}$
Nominal I-Region Width	$\mu$	—	$175 \mu\text{m}$	$300 \mu\text{m}$	$175 \mu\text{m}$	$100 \mu\text{m}$

### Maximum Rated Reverse Voltage ( $V_R$ ) vs. Model Numbers

Maximum Rated Reverse	MA4P4000 Series	MA4P4300 Series	MA4P7000 Series	MA4P7100 Series
100 Volts	MA4P4001B-402	MA4P4301B-402	MA4P7001F-1072T	MA4P7101B-401/401T*
100 Volts	MA4P4001BNM-402*	MA4P4301F-1091T	—	MA4P7101F-1072T
200 Volts	MA4P4002B-402	—	MA4P7002B-401T	MA4P7102B-401/401T
200 Volts	MA4P4002F-1091T	—	MA4P7002F-1072T	MA4P7102F-1072T
400 Volts	—	—	—	MA4P7104B-401/401T
400 Volts	—	—	—	MA4P7104F-1072T
600 Volts	MA4P4006B-402	—	MA4P7006B-401T	—
600 Volts	MA4P4006-1091T	—	MA4P7006F-1072T	—

*\*Note: Part numbers ending in suffix -402 and -401/401T are non-magnetic packages*

### Power Dissipation and Thermal Resistance Ratings @ $T_{AMB} = +25^{\circ}\text{C}$

Package Style	Condition	MA4P4000		MA4P4300		MA4P7000		MA4P7100	
		$P_{DISS}$	$\theta_{JC}$	$P_{DISS}$	$\theta_{JC}$	$P_{DISS}$	$\theta_{JC}$	$P_{DISS}$	$\theta_{JC}$
B Axial Leaded	1/4" Lead Length	12 W	$12.5^{\circ}\text{C/W}$	10 W	$15^{\circ}\text{C/W}$	5 W	$30^{\circ}\text{C/W}$	6 W	$25^{\circ}\text{C/W}$
	No Heatsink	2.5 W	—	2.5 W	—	1.5 W	—	1.5 W	—
F	Infinite Heatsink	7.5 W	$20^{\circ}\text{C/W}$	5 W	$30^{\circ}\text{C/W}$	3 W	$50^{\circ}\text{C/W}$	3 W	$50^{\circ}\text{C/W}$
Both B and F	Single $1 \mu\text{s}$ pulse	100 kW	—	100 kW	—	15 kW	—	15 kW	—
Both B and F	Single $100 \mu\text{s}$ pulse	5 kW	$0.03^{\circ}\text{C/W}$	5 kW	$0.03^{\circ}\text{C/W}$	300 W	$0.5^{\circ}\text{C/W}$	300 W	$0.5^{\circ}\text{C/W}$

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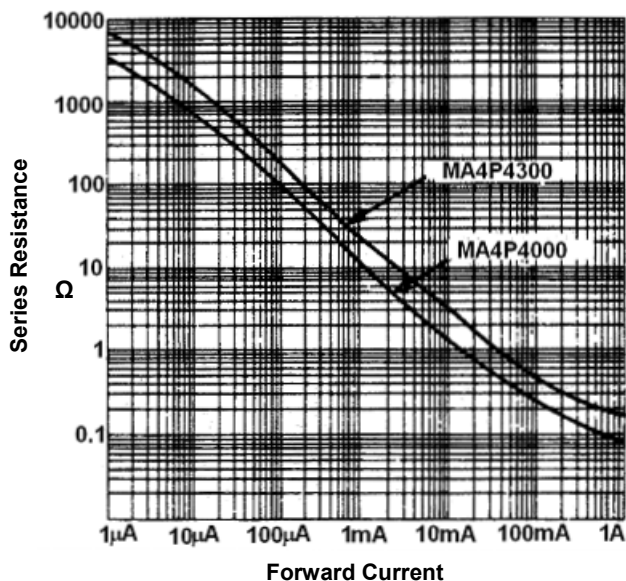
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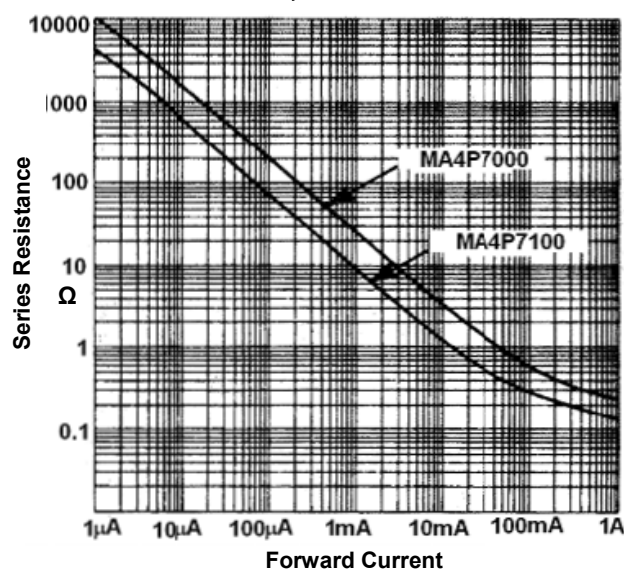
V12

### Typical Performance Curves @ $T_{AMB} = +25^{\circ}\text{C}$ MA4P4000, MA4P4300, MA4P7000, MA4P7100 Series

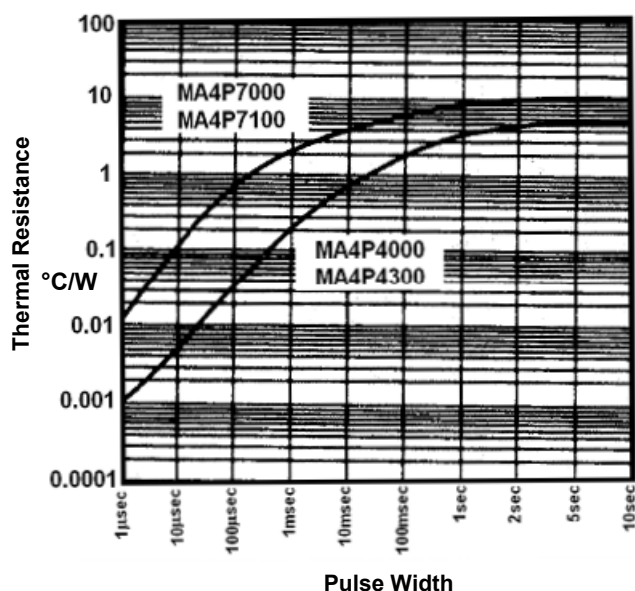
Series Resistance at 100 MHz vs. Forward Current  
MA4P4000, MA4P4300 Series



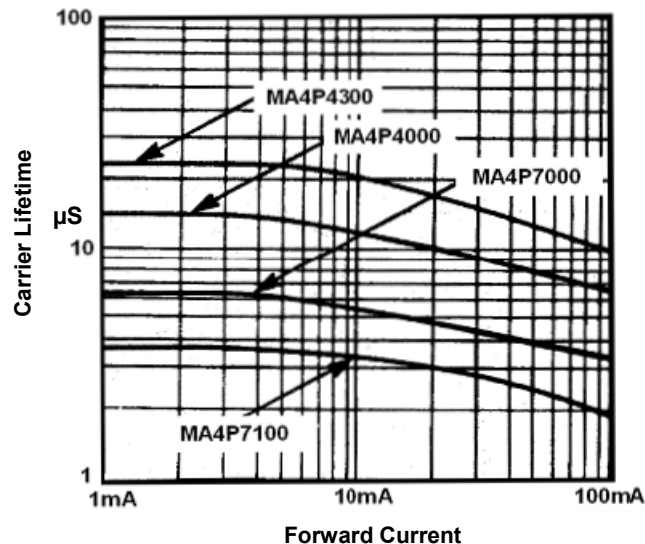
Series Resistance at 100 MHz vs. Forward Current  
MA4P7000, MA4P7100 Series



Thermal Resistance vs. Pulse Width  
MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



Carrier Lifetime vs. Forward Bias Current  
MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



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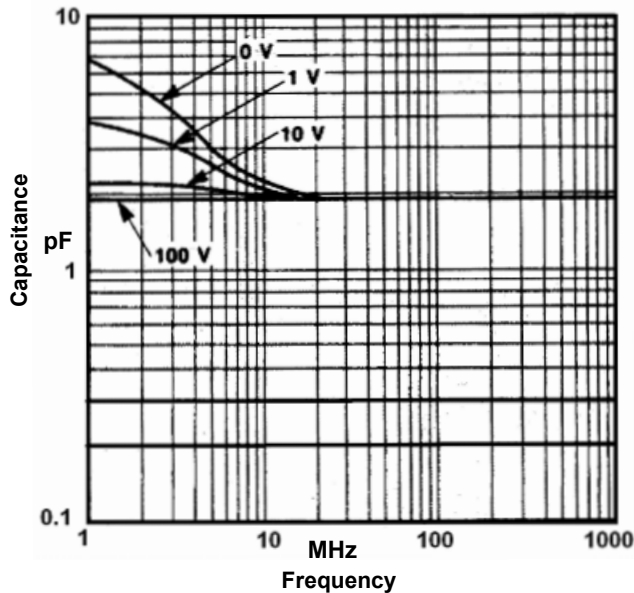
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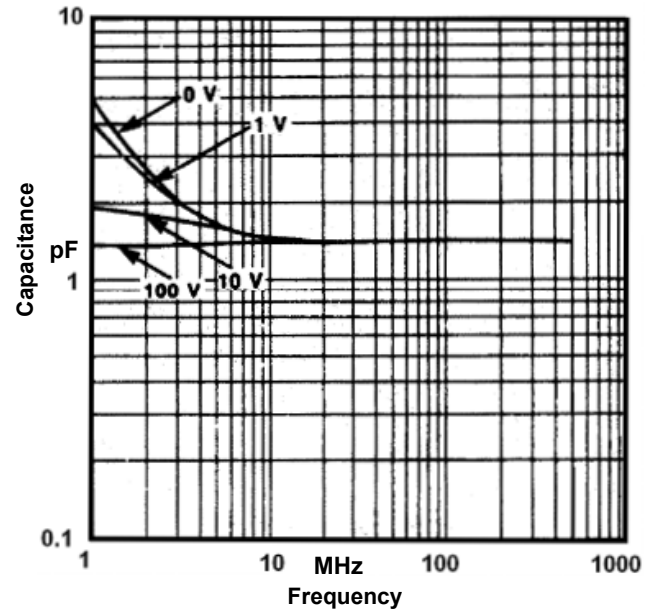
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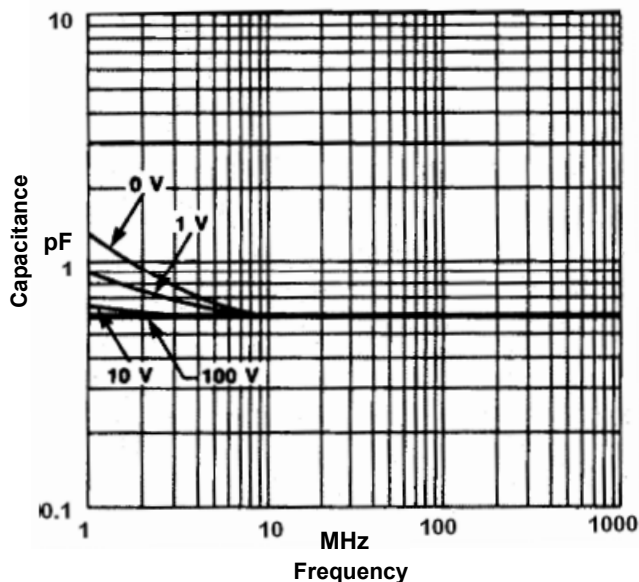
Capacitance vs. Frequency & Reverse Bias  
MA4P4000 Series



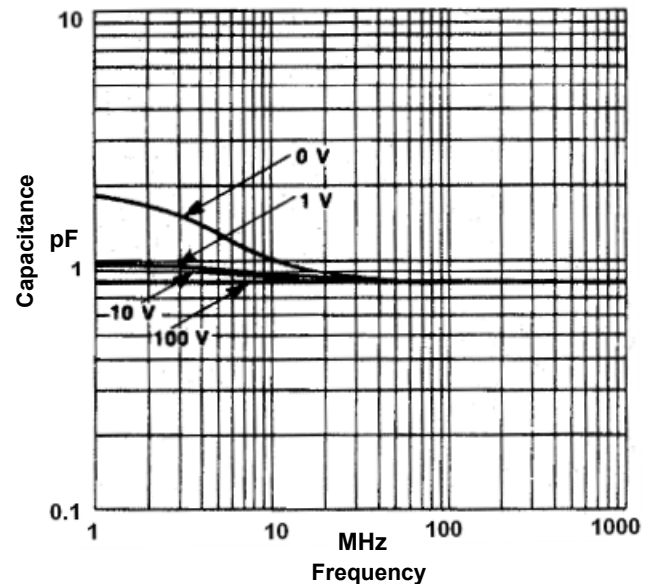
Capacitance vs. Frequency & Reverse Bias  
MA4P4300 Series



Capacitance vs. Frequency & Reverse Bias  
MA4P7000 Series



Capacitance vs. Frequency & Reverse Bias  
MA4P7100 Series



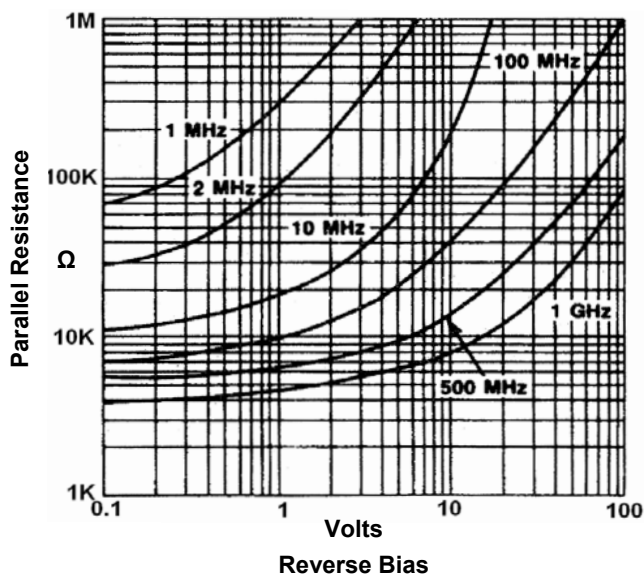


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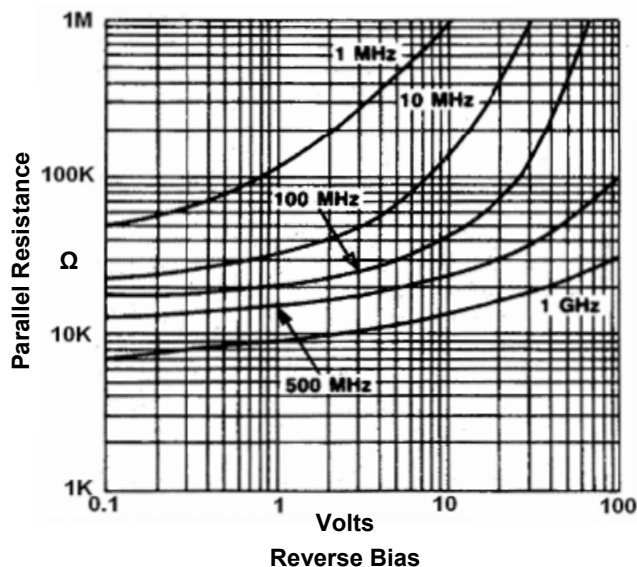
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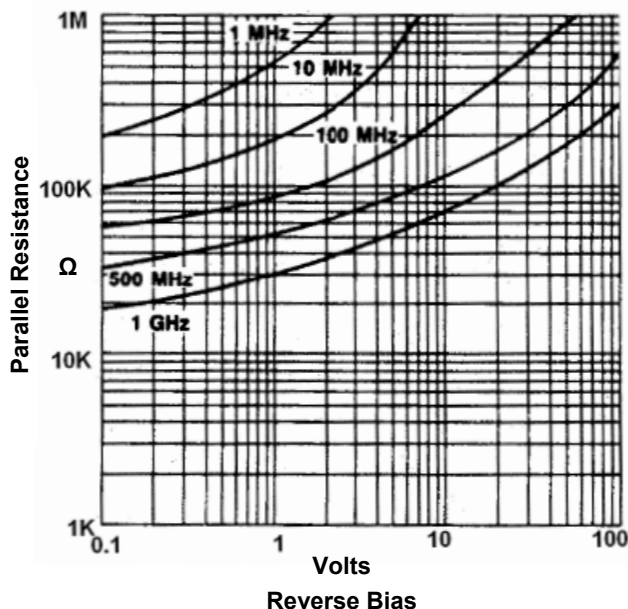
Parallel Resistance vs. Reverse Bias & Frequency  
MA4P4000 Series



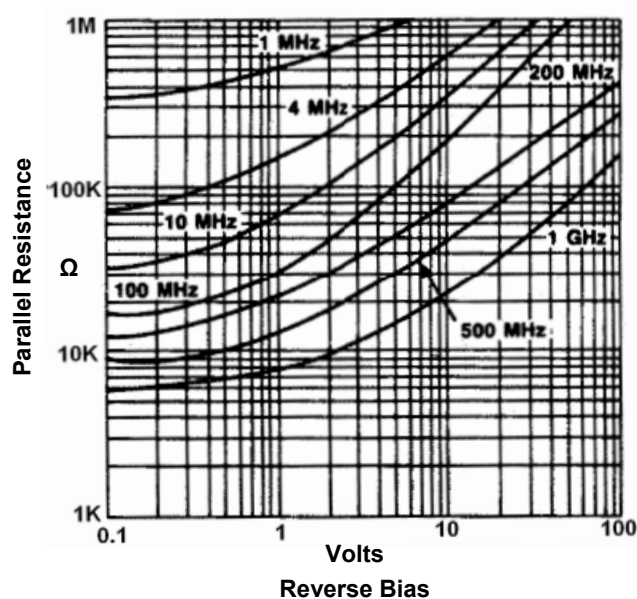
Parallel Resistance vs. Reverse Bias & Frequency  
MA4P4300 Series



Parallel Resistance vs. Reverse Bias & Frequency  
MA4P7000 Series



Parallel Resistance vs. Reverse Bias & Frequency  
MA4P7100 Series

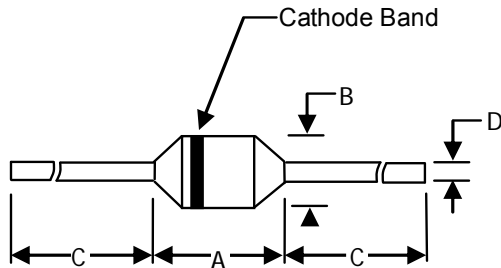


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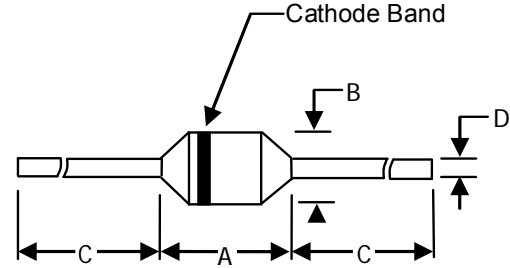
### Case Styles

#### 401 Axial Leaded Packages



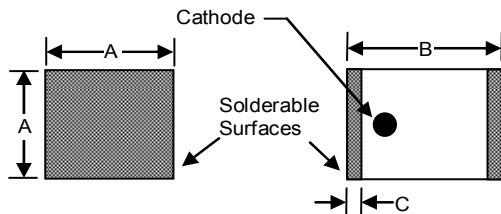
401 Package (tape and reel) 500 or 1000pcs/reel	Dimension	INCHES		MM	
		MIN.	MAX.	MIN.	MAX.
MA4P1200-401T	A	—	0.130	—	3.30
MA4P1200NM-401T	B	—	0.090	—	2.29
MA4P7002B-401T	C	0.975		24.77	—
MA4P7006B-401T	D	0.027	0.029	0.69	0.74
MA4P7101B-401T					
MA4P7102B-401T					
MA4P7104B-401T					

#### 402 Axial Leaded Packages



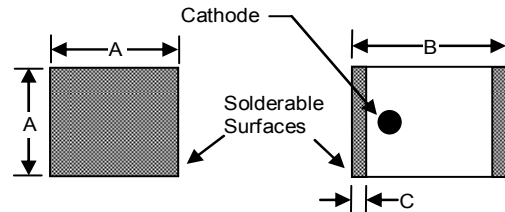
402 Package (bulk only) 100pcs/bag	Dimension	INCHES		MM	
		MIN.	MAX.	MIN.	MAX.
MA4P4001B-402	A	—	0.230	—	5.84
MA4P4001BNM-402	B	—	0.140	—	3.56
MA4P4002B-402	C	0.975		24.64	—
MA4P4006B-402	D	0.039	0.041	0.76	1.02
MA4P4301B-402					

#### 1091 MELF Surface Mount Packages



1091 Package (tape and reel only) 500pcs/reel	Dimension	INCHES		MM	
		MIN.	MAX.	MIN.	MAX.
MA4P1450-1091T	A	0.138	0.155	3.51	3.94
MA4P1450NM-1091T	B	0.180	0.200	4.57	5.08
MA4P4001F-1091T	C	0.008	0.030	0.203	0.762
MA4P4002F-1091T					
MA4P4006F-1091T					
MA4P4301F-1091T					

#### 1072 MELF Surface Mount Packages



1072 Package (tape and reel only) 1500pcs/reel	Dimension	INCHES		MM	
		MIN.	MAX.	MIN.	MAX.
MA4P1250-1072T	A	0.080	0.095	2.032	2.413
MA4P1250NM-1072T	B	0.115	0.135	2.921	3.429
MA4P7001F-1072T	C	0.008	0.030	0.203	0.762
MA4P7002F-1072T					
MA4P7006F-1072T					
MA4P7101F-1072T					
MA4P7104F-1072T					

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## High Power PIN Diodes

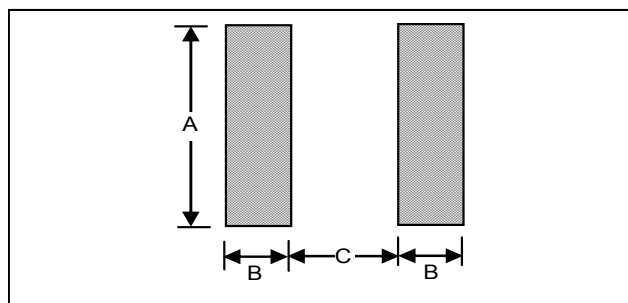
V12

### MELF Assembly Recommendations

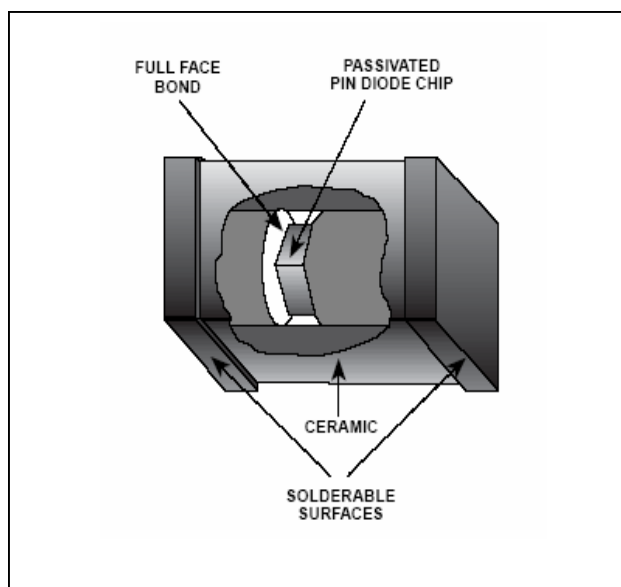
- ◆ Devices may be soldered using standard 60Sn/40Pb or RoHS compliant solders. Axial leads and solderable surfaces of MELF devices are tin plated 50  $\mu$ m thick to ensure an optimum connection.
- ◆ For recommended Sn/Pb and RoHS soldering profiles See Application Note [M538](#) on the M/A-COM website.

### Circuit Pad Layout for MELF Diodes

Dimension	Package Style 1072		Package Style 1091	
	inches	mm	inches	mm
A	0.093	2.36	0.150	3.81
B	0.050	1.27	0.050	1.27
C	0.060	1.52	0.100	2.54



### MELF Internal Construction



### Ordering Information

MELF diodes are available in tape and reel in quantities as shown in table below

Package Style	Quantity (7" Reel)	Bulk Devices Per Bag
1072T	1500	N/A
1091T	500	N/A

Tape and reel information can be found on the M/A-COM website [at http://www.macomtech.com/Application Notes/pdf/M513.pdf](http://www.macomtech.com/Application Notes/pdf/M513.pdf)

\*Specifications subject to change without notice

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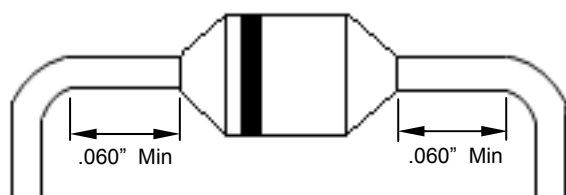
## High Power PIN Diodes

V12

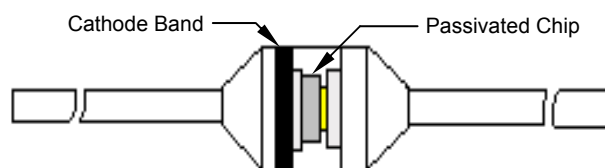
### Axial Leaded HIPAX Assembly Recommendations

- ◆ Bends on case styles 401 and 402, axially leaded devices, must be made while holding the lead firm and forming the bend no closer than .060 inches from the body of the part. Bending the lead < 0.060 inches from the body of the part is not recommended and may cause internal damage to the chip. Appropriate fixturing should be used.
- ◆ Devices may be soldered using standard 60Sn/40Pb or any RoHS compliant solders. Axial leads are tin plated 50μm thick to ensure an optimum connection.
- ◆ For recommended Sn/Pb and RoHS soldering profiles See Application Note [M538](#) on the M/A-COM website.

#### Case Style 401 & 402 Minimum Bend Distance



#### Case Style 401 & 402 Internal Construction



### Ordering Information

Axial leaded diodes are available in tape and reel or bulk in quantities shown in the table below

Package Style	Quantity Per Reel	Bulk Devices Per Bag
401T	500 or 1000	N/A
402	N/A	100

### Environmental Ratings

HIPAX PIN diodes are designed to meet most environmental and electrical requirements and may be ordered screened to MIL-STD-750 specifications as described in the table below.

TEST	METHOD	DESCRIPTION/ CONDITIONS
Moisture Resistance	1021	85°C, 85% Relative Humidity, 168 hrs
High Temperature Storage	1031	+175°C , 250 Hours
HTRB	1038	80% of rated $V_R$ , 50°C, 96 Hours
Temperature Shock	1051	-65°C to +175°C, 20 Cycles
Fine Leak	1071 Cond. H	$1 \times 10^{-7}$ CC/Sec
Constant Acceleration	2006	20,000 G's
Solderability	2026	IPC/JDEC J-STD-02
Tension <sup>1</sup>	2036.3 Cond. A	2 Lbs., 30 Seconds
Lead Fatigue <sup>1</sup>	2036.3 Cond. E	3 Cycles, 8 oz., 90°,

#### Note:

- 1) Test applicable to HIPAX axially leaded devices only.

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